

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application

Inventor: Jian Chen, et al.

Application No.: 10/765,693

Filed Date: January 26, 2004

Title: METHOD OF READING NAND MEMORY
TO COMPENSATE FOR COUPLING BETWEEN
STORAGE ELEMENTS

PATENT APPLICATION

Art Unit: 2824

Examiner: Tran, Andrew Q.

Customer No.: 64948

RESPONSE C TO OFFICE ACTION UNDER 37 C.F.R. § 1.116

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

This RESPONSE C is in reply to the Office Action mailed June 11, 2007 and the Advisory Action mailed September 25, 2007.

RESPONSE B, submitted September 11, 2007, is hereby withdrawn.

AMENDMENTS TO THE CLAIMS are reflected in the listing of claims which begin on page 2 of this Response.

AMENDMENTS TO THE ABSTRACT are reflected in the listing of claims which begin on page 6 of this Response.

REMARKS begin on Page 7 of this Response.